Analog Power AM30N10-70DE

N-Channel 100-V (D-S) MOSFET

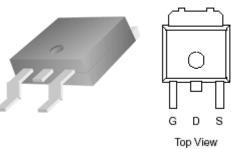
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$	$I_D(A)$		
100	$78 @ V_{CS} = 10V$	21		
	92 @ V _{cs} =4.5V	20		

TO-252

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe DPAK saves board space
- Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V_{DS}	100	V	
Cate-Source Voltage		V_{CS}	±20	·	
Continuous Drain Current ^a	T _C =25°C	I_D	20	A	
Pulsed Drain Current ^b		I_{DM}	36	A	
Continuous Source Current (Diode Conduction) ^a		I_S	30	Α	
Power Dissipation ^a	T _C =25°C	P_{D}	50	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C	

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	$R_{ heta JA}$	50	°C/W	
Maximum Junction-to-Case	$R_{ heta JC}$	3.0	°C/W	

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

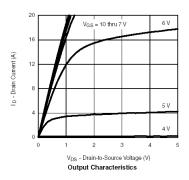
Parameter	Cross b al	T 4 C 114	Limits			T T 24	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1.0			V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	$I_{ m DSS}$	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Dram Current	DSS	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uД	
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	34			A	
Drain-Source On-Resistance ^A	r	$V_{GS} = 10 \text{ V}, I_D = 9.2 \text{ A}$			78	mΩ	
Drain-Source On-Resistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 6.1 \text{ A}$			92		
Forward Tranconductance ^A	${f g}_{ m fs}$	$V_{DS} = 40 \text{ V}, I_{D} = 5.5 \text{ A}$		20		S	
Diode Forward Voltage	V_{SD}	$I_S = 9 \text{ A}, V_{GS} = 0 \text{ V}$		0.8		V	
Dynamic ^b					-	•	
Total Gate Charge	Q_{g}	$V_{DS} = 50 \text{ V}, V_{GS} = 4.5 \text{ V},$		21			
Gate-Source Charge	Q_{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 4.3 \text{ V},$ $I_{D} = 9 \text{ A}$		3.8		nC	
Gate-Drain Charge	Q_{gd}			14.2			
Turn-On Delay Time	$t_{d(on)}$			7.5			
Rise Time	t _r	$V_{DD} = 50 \text{ V}, R_L = 5.2 \Omega, I_D = 9 \text{ A},$		13.6		nS	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}$		41		113	
Fall-Time	t _f			35			

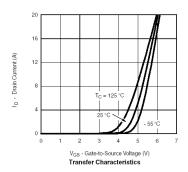
Notes

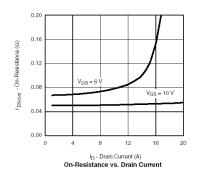
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

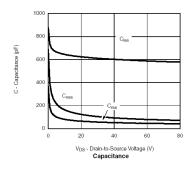
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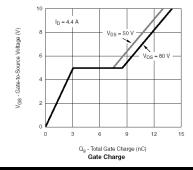
Typical Electrical Characteristics (N-Channel)

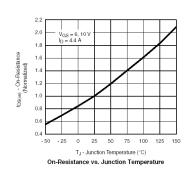






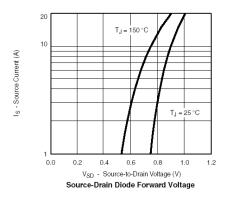


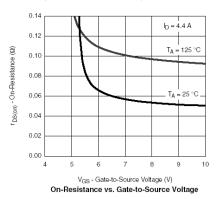


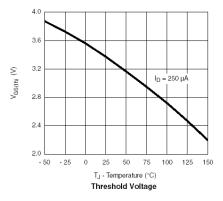


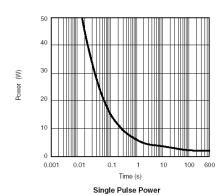
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Typical Electrical Characteristics (N-Channel)









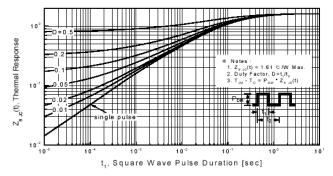
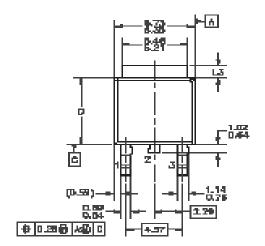
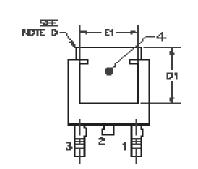
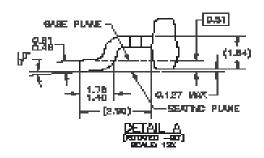


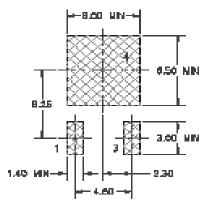
Figure 11. Transient Thermal Response Curve

Package Information

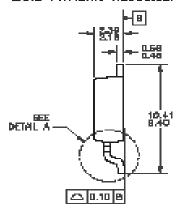








LAND PATTERN RECOMMENDATION



NOTES: UNLESS OTHERWISE SPECIFIED

- ALL DIPERSONS ARE IN INCLINETERS.
 THIS PRODUCE CONFORMS TO JEDEC, TO-262,
 188UE C, VARIATION AS IN 68, DATED NOW 1989.
 DIMENSIONING AND TOLERANGING PER
- MANE THANH-1884.
 HEAT SINK TOP EDGE COULD BE IN CHANFERED
 CORRESS OR EDGE PROTRUSION.
 DIMENSIONS 13,0,61401 TABLE:

	OPTION JAI	97TUT AT
	0.0 -1.27	1.82-7.00
	0.4 []0.12	0.44-0.40
	4.42	3.81 MM
n I	7 17 1	4.47